L Number	Hits	Search Text	DB	Time stamp
1	2	(("5372967") or ("6236538")).PN.	USPAT;	2004/05/04 09:05
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB	
2	1406967	cylind\$8 rod circle "semi-circle" semi near3 cycle	USPAT;	2004/05/04 09:07
_	1100507	Symass road short Somm choic Somm means syste	US-PGPUB	2004/03/04 07:07
3	48673	inductor	USPAT;	2004/05/04 09:07
3	40075	inductor	US-PGPUB	2004/03/04 09:07
4	11849	(cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor	1	2004/05/04 00 00
7	11049	(cylinda o rod chele semi-chele semi nears cycle) and inductor	USPAT;	2004/05/04 09:09
5	399609	semiconductor	US-PGPUB	2004/05/04 00 10
,	399009	Semiconductor	USPAT;	2004/05/04 09:10
	404673		US-PGPUB	
6	404672	semiconductor semiconductive	USPAT;	2004/05/04 09:10
_	2105	// 12 100 1 / 1 ll l	US-PGPUB	
7	3107	((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:10
_		(semiconductor semiconductive)	US-PGPUB	
8	627772	substrate	USPAT;	2004/05/04 09:10
			US-PGPUB	
9	1688	(((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:10
İ		(semiconductor semiconductive)) and substrate	US-PGPUB	
10	573264	groove trench	USPAT;	2004/05/04 09:11
			US-PGPUB	
11	534	((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:11
		(semiconductor semiconductive)) and substrate) and (groove trench)	US-PGPUB	
12	355	(((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:33
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	200 11 057 0 1 05.55
ļ		@ad<20010831	COTOLOB	
13	855982	insulating insulator oxide	USPAT;	2004/05/04 11:24
		mountain ontain	US-PGPUB	2004/03/04 11.24
14	30770	(groove trench) with (insulating insulator oxide)	USPAT;	2004/05/04 09:21
•	30770	(groove action) with (modiating modiator oxide)	US-PGPUB	2004/03/04 09:21
15	75	((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	1	2004/05/04 00 22
13	,3	(semiconductor semiconductive)) and substrate) and (groove trench)) and	USPAT;	2004/05/04 09:32
İ		(groove trench) and (groove trench) with (insulating insulator oxide)	US-PGPUB	
16	5		LIGDAT	2004/05/04 00 04
17	4	("3305814" "5008176" "5112438" "5748523" "6303971").PN. ("3290758" "3614554" "5372967" "5514832").PN.	USPAT	2004/05/04 09:26
18	280		USPAT	2004/05/04 09:30
10	200	((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:33
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	
		@ad<20010831) not (((((((cylind\$8 rod circle "semi-circle" semi near3 cycle		
1	:) and inductor) and (semiconductor semiconductive)) and substrate) and		
		(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
		insulator oxide)))		
19	131	(((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:38
1		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	
		@ad<20010831) not (((((((cylind\$8 rod circle "semi-circle" semi near3 cycle		
İ) and inductor) and (semiconductor semiconductive)) and substrate) and		
		(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
		insulator oxide)))) and @ad<19971119		
20	666	inductor and ((groove trench) with (insulating insulator oxide))	USPAT;	2004/05/04 09:38
			US-PGPUB	
21	591	(inductor and ((groove trench) with (insulating insulator oxide))) not	USPAT;	2004/05/04 09:38
		(((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	US-PGPUB	200 11 05/ 04 07.50
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	55 T GI GB	
		@ad<20010831) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle		
İ	İ) and inductor) and (semiconductor semiconductive)) and substrate) and		
	ĺ	(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
1				
		insulator oxide)))) not (((((((cylind\$8 rod circle "semi-circle" semi near3		
		cycle) and inductor) and (semiconductor semiconductive)) and substrate)		
		and (groove trench)) and @ad<20010831) and ((groove trench) with		
		(insulating insulator oxide)))		

22	149	((inductor and ((groove trench) with (insulating insulator oxide))) not	USPAT;	2004/05/04 10:13
		(((((((cylind\$8 rod circle "semi-circle" semi near3 cycle)) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) not (((((((cylind\$8 rod circle "semi-circle" semi near3 cycle	US-PGPUB	
) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
		insulator oxide)))) not ((((((cylind\$8 rod circle "semi-circle" semi near3		
		cycle) and inductor) and (semiconductor semiconductive)) and substrate)		
22	22010	and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide)))) and @ad<19971119		
23	33818	magnetic near4 core	USPAT; US-PGPUB	2004/05/04 10:09
24	95347	inductor inductive	USPAT; US-PGPUB	2004/05/04 11:07
25	7747	(magnetic near4 core) and (inductor inductive)	USPAT; US-PGPUB	2004/05/04 10:10
26	1741	(semiconductor semiconductive) and ((magnetic near4 core) and (inductor inductive))	USPAT; US-PGPUB	2004/05/04 10:10
27	25318	(semiconductor semiconductive) and (inductor inductive)	USPAT; US-PGPUB	2004/05/04 10:10
28	23577	((semiconductor semiconductive) and (inductor inductive)) not ((semiconductor semiconductive) and ((magnetic near4 core) and (inductor	USPAT; US-PGPUB	2004/05/04 10:11
29	375966	inductive))) core	USPAT;	2004/05/04 11:23
30	23493	(insulating insulator oxide) with core	US-PGPUB USPAT;	2004/05/04 11:23
31	2156	(inductor inductive) and ((insulating insulator oxide) with core)	US-PGPUB USPAT;	2004/05/04 10:12
32	494	(semiconductor semiconductive) and ((inductor inductive) and ((insulating	US-PGPUB USPAT;	2004/05/04 10:28
33	177	insulator oxide) with core)) ((semiconductor semiconductive) and ((inductor inductive) and ((insulating	US-PGPUB USPAT;	2004/05/04 10:29
34	3650	insulator oxide) with core))) and @ad<19971119 (semiconductor semiconductive) and ((insulating insulator oxide) with core)	US-PGPUB USPAT;	2004/05/04 10:29
35	396677	coil	US-PGPUB USPAT;	2004/05/04 10:29
36	920	((semiconductor semiconductive) and ((insulating insulator oxide) with	US-PGPUB USPAT;	2004/05/04 10:29
37	393	core)) and coil (((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119	US-PGPUB USPAT;	2004/05/04 11:19
38	265	((((semiconductor semiconductive) and ((insulating insulator oxide) with	US-PGPUB USPAT;	2004/05/04 10:30
		core)) and coil) and @ad<19971119) not (((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119)	US-PGPUB	
39	103	substrate and (((((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119) not (((semiconductor	USPAT;	2004/05/04 11:06
		semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119))	US-PGPUB	
40	62585	polysilicon	USPAT; US-PGPUB	2004/05/04 11:38
41	454129	inductor inductive coil	USPAT; US-PGPUB	2004/05/04 11:38
42	4231	polysilicon and (inductor inductive coil)	USPAT; US-PGPUB	2004/05/04 11:07
43	1276	(polysilicon and (inductor inductive coil)) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:08
44	70/320	((insulating insulator oxide) with core) and ((polysilicon and (inductor inductive coil)) and @ad<19971119)	USPAT; US-PGPUB	2004/05/04 11:17
45	796328	oxid\$6	USPAT; US-PGPUB	2004/05/04 11:36
46	71504	(inductor inductive coil) and oxid\$6	USPAT; US-PGPUB	2004/05/04 11:18
47	40416	((inductor inductive coil) and oxid\$6) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:25

48	1022	polysilicon and (((inductor inductive coil) and oxid\$6) and @ad<19971119)	USPAT;	2004/05/04 11:19
49	16	((insulating insulator oxide) with core) and (polysilicon and (((inductor	US-PGPUB USPAT;	2004/05/04 11:20
"		inductive coil) and oxid\$6) and @ad<19971119))	US-PGPUB	2004/05/04 11:20
50	234540	inductor inductive coil	EPO; JPO;	2004/05/04 11:29
			IBM_TDB	
51	211236	core	EPO; JPO;	2004/05/04 11:28
50	470406		IBM_TDB	2004/05/04 11 20
52	479495	insulating insulator oxide	EPO; JPO;	2004/05/04 11:28
53	5126	(inductor inductive coil) and core and (insulating insulator oxide)	IBM_TDB EPO; JPO;	2004/05/04 11:26
33	3120	(madetor inductive con) and core and (madating insulator oxide)	IBM TDB	2004/05/04 11:20
54	2634	(inductor inductive coil) with core with (insulating insulator oxide)	EPO; JPO;	2004/05/04 11:24
			IBM TDB	
55	0	((inductor inductive coil) with core with (insulating insulator oxide)) and	USPĀT;	2004/05/04 11:50
_		@ad<19971119	US-PGPUB	
56	13068	polysilicon	ЈРО;	2004/05/04 11:27
			IBM_TDB	
57	1	((inductor inductive coil) with core with (insulating insulator oxide)) and	JPO;	2004/05/04 11:27
58	,	polysilicon ((inductor inductive coil) and core and (insulating insulator oxide)) and	IBM_TDB	2004/05/04 11 27
38	1	polysilicon	EPO; JPO;	2004/05/04 11:27
59	14448	polysilicon	IBM_TDB EPO; JPO;	2004/05/04 11:30
	''''	polysincon	IBM TDB	2004/03/04 11.30
60	1	((inductor inductive coil) with core with (insulating insulator oxide)) and	JPO;	2004/05/04 11:27
		polysilicon	IBM TDB	2001/05/01/11/2/
61	290275	core	DERWENT	2004/05/04 11:28
62	714947	insulating insulator oxide	DERWENT	2004/05/04 11:28
63	300876	inductor inductive coil	DERWENT	2004/05/04 11:29
64	2489	core same (insulating insulator oxide) same (inductor inductive coil)	DERWENT	2004/05/04 11:29
65	1547	core with (insulating insulator oxide) with (inductor inductive coil)	DERWENT	2004/05/04 11:29
66	16371	polysilicon	DERWENT	2004/05/04 11:30
67	2	(core with (insulating insulator oxide) with (inductor inductive coil)) and	DERWENT	2004/05/04 11:32
68	1	polysilicon	T IOD A M	0004/07/0444
00	1	("6015742").PN.	USPAT;	2004/05/04 11:32
69	8	("3988764" "5372967" "5514832" "5767563" "5770509" "5825092"	US-PGPUB USPAT	2004/05/04 11:32
0)		(3500764 3572507 3514632 3707303 3770309 3823092	USFAI	2004/03/04 11:32
70	238208	oxidi\$5	USPAT:	2004/05/04 11:36
			US-PGPUB	2004/05/04 11:50
71	0	polysilicon with oxidi\$5	USPAT;	2004/05/04 11:36
			US-PGPUB	
72	4081	polysilicon with oxidi\$5	USPAT;	2004/05/04 11:38
			US-PGPUB	
73	149	(inductor inductive coil) and (polysilicon with oxidi\$5)	USPAT;	2004/05/04 11:39
7.			US-PGPUB	
74	56	((inductor inductive coil) and (polysilicon with oxidi\$5)) and	USPAT;	2004/05/04 11:51
	<u>L</u>	@ad<19971119	US-PGPUB	